RoHS COMPLIANT

Vishay High Power Products

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TO-200AB (E-PUK)

PRODUCT SUMMARY					
I _{T(AV)}	960 A				

FEATURES

Phase Control Thyristors (Hockey PUK Version), 960 A

- Center amplifying gate
- · Metal case with ceramic insulator
- International standard case TO-200AB (E-PUK)
- · Low profile hockey PUK to increase current-carrying capability
- · Lead (Pb)-free
- · Designed and qualified for industrial level

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
1		960	А				
I _{T(AV)}	T _{hs}	55	°C				
1		1900	А				
I _T (RMS)	T _{hs}	25	°C				
I _{TSM}	50 Hz	15 000	A				
	60 Hz	15 700	A				
l ² t	50 Hz	1130	kA ² s				
1-1	60 Hz	1030	KA-S				
V _{DRM} /V _{RRM}		400/600	V				
tq	Typical	100	μs				
TJ		- 40 to 125	۵°				

ELECTRICAL SPECIFICATIONS

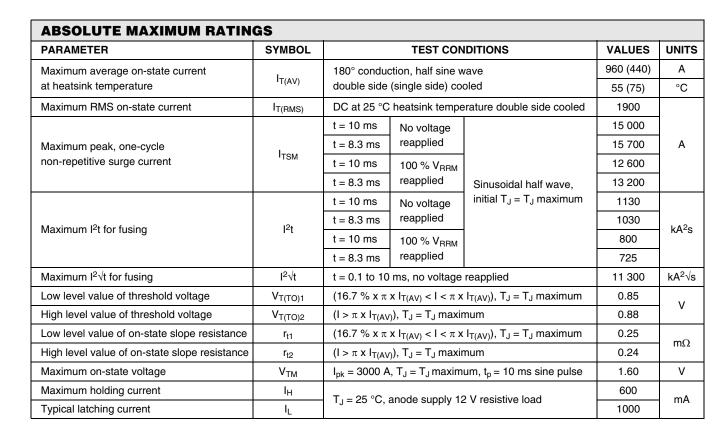
VOLTAGE RATINGS										
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM} MAXIMUM AT T_J = T_J MAXIMUM mA$						
ST380CC	04	400	500	50						
0100000	06	600	700	00						





ST380CPbF Series

Vishay High Power Products Phase Control Thyristors (Hockey PUK Version), 960 A



SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 $\Omega, t_r \leq$ 1 μs T_J = T_J maximum, anode voltage \leq 80 % V_{DRM}	1000	A/µs				
Typical delay time	t _d	Gate current 1 A, dl _g /dt = 1 A/ μ s V _d = 0.67 % V _{DRM} , T _J = 25 °C	1.0	10				
Typical turn-off time	tq	I_{TM} = 550 A, T_J = T_J maximum, dl/dt = 40 A/µs, V_R = 50 V, dV/dt = 20 V/µs, gate 0 V 100 $\Omega,$ t_p = 500 µs	100	μs				

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs				
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	50	mA				



Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 960 A

TRIGGERING							
PARAMETER	CYMPOL	SYMBOL TEST CONDITIONS			UES		
PARAMETER	STNDUL				MAX.	UNITS	
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	10	0.0	w	
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	vv	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	3	.0	А	
Maximum peak positive gate voltage	+ V _{GM}	+ V _{GM}		2	20	v	
Maximum peak negative gate voltage	- V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms			.0	v	
		T _J = - 40 °C		200	-		
DC gate current required to trigger	I _{GT}	T _J = 25 °C	Maximum required gate trigger/	100	200	mA	
		T _J = 125 °C	current/voltage are the lowest	50	-		
		T _J = - 40 °C	value which will trigger all units	2.5	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C	12 V anode to cathode applied	1.8	3.0	V	
		T _J = 125 °C		1.1	-		
DC gate current not to trigger	I _{GD}		Maximum gate current/voltage not to trigger is the maximum	10		mA	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J$ maximum	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.	25	v	

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum operating junction temperature range	TJ		- 40 to 125	0			
Maximum storage temperature range	T _{Stg}		- 40 to 150				
Movimum thermal registered junction to bestainly	D	DC operation single side cooled	0.09				
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation double side cooled	0.04	κ/w			
Maximum thermal registeres, sees to besteink	Р	DC operation single side cooled	0.02	r\/ vv			
Maximum thermal resistance, case to heatsink	R _{thC-hs}	DC operation double side cooled	0.01				
Mounting force, ± 10 %			9800 (1000)	N (kg)			
Approximate weight			83	g			
Case style		See dimensions - link at the end of datasheet	TO-200AB (E-PUK)			

CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULA	R CONDUCTION	TECT CONDITIONS	UNITS			
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS			
180°	0.010	0.011	0.007	0.007					
120°	0.012	0.012	0.012	0.013					
90°	0.015	0.015	0.016	0.017	$T_J = T_J$ maximum	K/W			
60°	0.022	0.022	0.023	0.023					
30°	0.036	0.036	0.036	0.037					

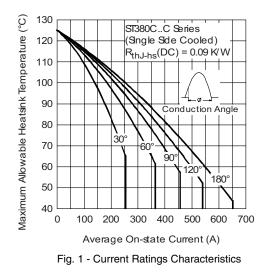
Note

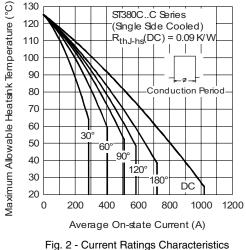
• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

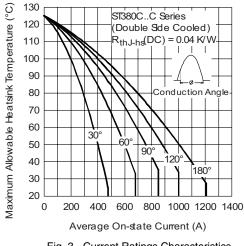
ST380CPbF Series

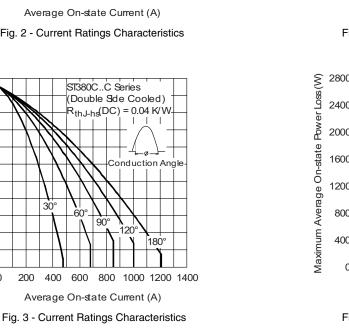
Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 960 A











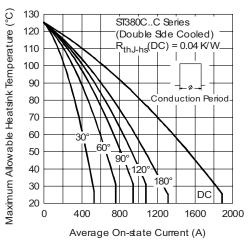
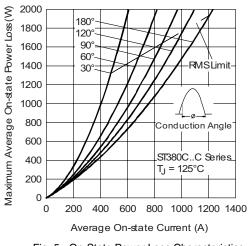
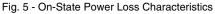


Fig. 4 - Current Ratings Characteristics





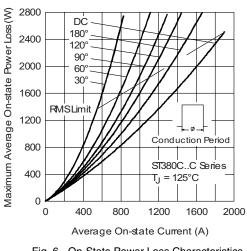
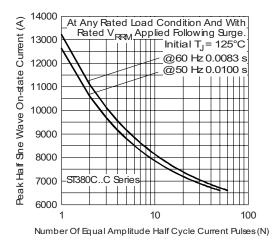


Fig. 6 - On-State Power Loss Characteristics



Phase Control Thyristors Vishay High Power Products (Hockey PUK Version), 960 A





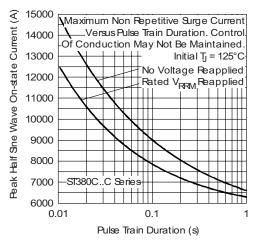


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

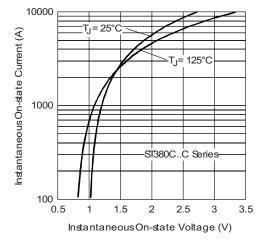


Fig. 9 - On-State Voltage Drop Characteristics

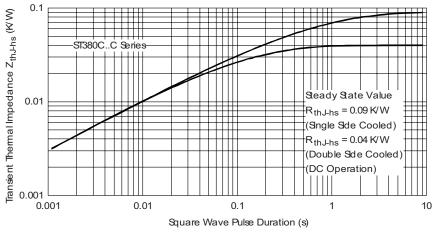


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

ST380CPbF Series



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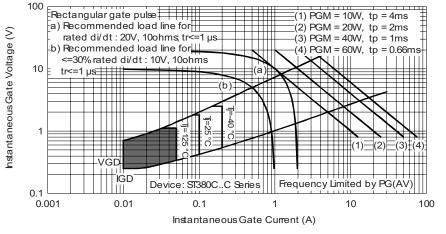


Fig. 11 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code	ST	38	0	с	06	С	1	-	PbF
		2	3	4	5	6	7	8	9
	1 -	Thy	ristor						
	2 -	-		art numl	ber				
	3 -	0 =	Conver	ter grad	е				
	4 -	C =	Cerami	ic PUK					
	5 -	Volt	age coo	de x 100	= V _{RRM}	/ (see V	oltage F	Ratings	table)
	6 -	C =	PUK ca	ase TO-2	200AB (E-PUK)	1		
	7 -	0 =	Eyelet t	erminal	s (gate a	and aux	iliary ca	thode u	insolder
		1 =	Fast-on	termina	ıls (gate	and au	xiliary c	athode	unsolde
		2 =	Eyelet t	erminals	s (gate a	and aux	iliary ca	thode s	oldered
	_	3 =	Fast-on	termina	ls (gate	and au	xiliary c	athode	soldere
	8 -	Crit	ical dV/	dt: • No	ne = 50	0 V/µs (standa	d selec	tion)
	_			• L =	1000 \	//µs (sp	ecial se	lection)	
	9 -	Lea	d (Pb)-f	ree					

LINKS TO RELATED DOCUMENTS						
Dimensions http://www.vishay.com/doc?95075						

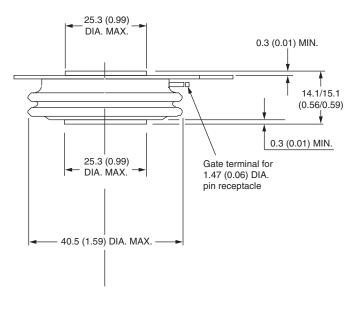


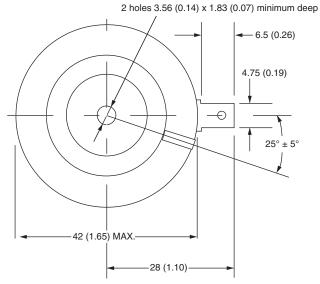
Vishay Semiconductors

TO-200AB (E-PUK)

DIMENSIONS in millimeters (inches)

Anode to gate Creepage distance: 11.18 (0.44) minimum Strike distance: 7.62 (0.30) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)



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